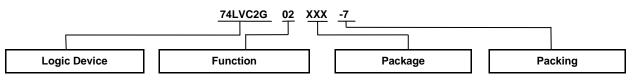


Ordering Information (Note 4)



74 : Logic Prefix LVC: 1.65V to 5.5V Logic Family 2G: Dual Gate

2-Input NOR Gate

02:

HD4: X2-DFN2010-8 HK3: X2-DFN1410-8 RA3: X2-DFN1210-8

-7: 7" Tape & Reel

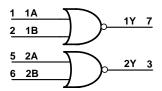
	Package	Package	Package	7" Tape and Re	el (Note 6)
Device	Code	(Note 5)	Size	Quantity	Part Number Suffix
74LVC2G02HD4-7	HD4	X2-DFN2010-8	1.95mm x 1.0mm x 0.4mm 0.5 mm lead pitch	5,000/Tape & Reel	-7
74LVC2G02HK3-7	HK3	X2-DFN1410-8	1.35mm x 1.0mm x 0.35mm 0.4 mm lead pitch	5,000/Tape & Reel	-7
74LVC2G02RA3-7	RA3	X2-DFN1210-8	1.2mm x 1.0mm x 0.35mm 0.3 mm lead pitch	5,000/Tape & Reel	-7

- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.
- Pad layout as shown in Diodes Incorporated's package outline PDFs, which can be found on our website at http://www.diodes.com/package-outlines.html.
 The taping orientation is located on our website at http://www.diodes.com/datasheets/ap02007.pdf.

Pin Descriptions

Pin Name	Pin No.	Description
1A	1	Data Input
1B	2	Data Input
2Y	3	Data Output
GND	4	Ground
2A	5	Data Input
2B	6	Data Input
1Y	7	Data Output
V _{CC}	8	Supply Voltage

Logic Diagram



Function Table

Inp	Output	
Α	В	Y
L	L	Н
L	Н	L
Н	L	L
Н	Н	L



Absolute Maximum Ratings (Notes 7 & 8)

Symbol	Description	Rating	Unit
ESD HBM	Human Body Model ESD Protection	2	kV
ESD CDM	Charged Device Model ESD Protection	1	kV
Vcc	Supply Voltage	-0.5 to +6.5	V
VI	Input Voltage	-0.5 to +6.5	V
Vo	Output Voltage -Active Mode	-0.5 to V _{CC} +0.5	V
VO	Output Voltage Power Down Mode	-0.5 to +6.5	V
I _{IK}	Input Clamp Current V _I <0	-50	mA
lok	Output Clamp Current (Vo < 0 OR Vo > Vcc)	±50	mA
lo	Continuous Output Current (Vo = 0 to V _{CC})	±50	mA
Icc	Continuous Current Through V _{CC}	100	mA
I _{GND}	Continuous Current Through GND	-100	mA
TJ	Operating Junction Temperature	-40 to +150	°C
T _{STG}	Storage Temperature	-65 to +150	°C

Notes:

Recommended Operating Conditions (Note 9)

Symbol	Pa	Parameter		Max	Unit
.,	On avatia a Malta va	Operating	1.65	5.5	V
Vcc	Operating Voltage	Data Retention Only	1.5	_	V
VI	Input Voltage		0	5.5	V
	Output Voltage Active Mode		0	V _{CC}	V
Vo	Output Voltage Power-Down Mode		0	5.5	V
	I _{OH} High-Level Output Current	V _{CC} = 1.65V	_	-4	
		V _{CC} = 2.3V	_	-8	
		V _{CC} = 2.7V	_	-12	mA
ЮН		V _{CC} = 3.0V	_	-16	
			_	-24	
		V _{CC} = 4.5V	_	-32	
		V _{CC} = 1.65V	_	4	
		V _{CC} = 2.3V	_	8	
I.e.	Low-Level Output Current	V _{CC} = 2.7V	_	12	mA
loL	Low-Level Output Current	V 2.0V	_	16	IIIA
		$V_{CC} = 3.0V$	_	24	
		V _{CC} = 4.5V		32	
Δt/ΔV	Input Transition Bigs or Fell Bate	V _{CC} = 1.65V to 2.7V	_	20	20/1
ΔυΔν	Input Transition Rise or Fall Rate	V _{CC} = 2.7V to 5.5V	_	10	ns/V
T _A	Operating Fr	ee-Air Temperature	-40	+125	°C

Note: 9. Unused inputs should be held at V_{CC} or Ground.

^{7.} Stresses beyond the absolute maximum may result in immediate failure or reduced reliability. These are stress values and device

operation should be within recommend values.

8. Forcing the maximum allowed voltage could cause a condition exceeding the maximum current or conversely forcing the maximum current could cause a condition exceeding the maximum voltage. The ratings of both current and voltage must be maintained within the controlled range.



Electrical Characteristics (All typical values are at T_A = +25°C)

	_		.,	-40	°C to +8	5°C	-40°C to	+125°C	
Symbol	Parameter	Test Conditions	V _{cc}	Min	Тур.	Max	Min	Max	Unit
			$V_{CC} = 1.65V \text{ to } 1.95V$	0.65 x V _{CC}	_	_	0.65 x V _{CC}	_	
.,	High-Level		V _{CC} = 2.3V to 2.7V	1.7	-	_	1.7	_	Ī.,
V_{IH}	Input Voltage	_	V _{CC} = 2.7V to 3.6V	2.0	_	_	2.0	_	V
			V _{CC} = 4.5V to 5.5V	0.7 x V _{CC}	_	_	0.7 x V _{CC}	_	
			$V_{CC} = 1.65V \text{ to } 1.95V$	_	_	0.35 x V _{CC}	_	0.35 x V _{CC}	
.,	Low-Level		V _{CC} = 2.3V to 2.7V	_	_	0.7	_	0.7	1
V_{IL}	Input Voltage	_	V _{CC} = 2.7V to 3.6V	_	_	0.8	_	0.8	V
			V _{CC} = 4.5V to 5.5V	_	_	0.3 x V _{CC}	_	0.3 x V _{CC}	
		I _{OH} = -100μA	1.65V to 5.5V	V _{CC} – 0.1	Vcc	_	V _{CC} – 0.1	_	
		I _{OH} = -4mA	1.65V	1.2	1.53	_	0.95	_	
	High-Level	$I_{OH} = -8mA$	2.3V	1.9	2.13	_	1.7	_	
Vон	Output	I _{OH} = -12mA	2.7	2.2	2.5	_	1.9	_	V
	Voltage	I _{OH} = -16mA	0) /	2.4	2.7	_	2.2	_	
		I _{OH} = -24mA	3V	2.3	2.6	_	2.0	_	
		I _{OH} = -32mA	4.5V	3.8	4.1	_	3.4	_	
		I _{OL} = 100μA	1.65V to 5.5V	_	0	0.1	_	0.1	
		I _{OL} = 4mA	1.65V	_	0.08	0.45	_	0.7	
	Low-Level	$I_{OL} = 8mA$	2.3V	_	0.14	0.3	_	0.45	V
V_{OL}	Output	$I_{OL} = 12mA$	2.7V	_	0.19	0.4	_	0.6	
	Voltage	I _{OL} = 16mA	0)/	_	0.25	0.4	_	0.6	
		$I_{OL} = 24mA$	3V	_	0.37	0.55	_	0.8	
		I _{OL} = 32mA	4.5V	_	0.43	0.55	_	0.8	
II	Input Current	V _I = 5.5V or GND	0V to 5.5V	_	± 0.1	±5	_	± 20	μΑ
I _{OFF}	Power Down Leakage Current	V_1 or $V_0 = 5.5V$	0V	_	± 0.1	±10	_	±20	μA
I _{CC}	Supply Current	$V_I = 5.5V$ or GND $I_O=0A$	1.65V to 5.5V	_	0.1	10	_	40	μA
ΔI _{CC}	Additional Supply Current	One input at V _{CC} – 0.6V Other inputs at V _{CC} or GND	2.3V to 5.5V	_	5	500	_	5,000	μА
Cı	Input Capacitance	V _I = V _{CC} or GND	3.3V	_	2.5	_	_	_	рF



Operating Characteristics

	Parameter	Test Conditions	V _{CC} = 1.8V Typ.	V _{CC} = 2.5V Typ.	V _{CC} = 3.3V Typ.	V _{CC} = 5V Typ.	Unit
C_{pd}	Power Dissipation Capacitance	f = 10MHz	18	18	19	22	pF

Package Characteristics

Symbol	Parameter	Package	Test Conditions	Min	Тур.	Max	Unit
		X2-DFN2010-8		-	313	-	
θ_{JA}	Thermal Resistance Junction- to-Ambient	X2-DFN1410-8	(Note 10)	_	321	_	°C/W
	to-Ambient	X2-DFN1210-8		_	395	_	
	- 15 1	X2-DFN2010-8	(Note 10)	_	145	_	
θ_{JC}	Thermal Resistance Junction-	X2-DFN1410-8		_	166	_	°C/W
	to-Case	X2-DFN1210-8		-	236	_	

Note: 10. Test condition for each package type: Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.

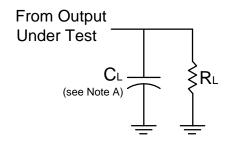
Switching Characteristics

Typical Values at $T_A = +25$ °C and nominal voltages 1.8V, 2.5V, 2.7V, 3.3V, and 5.0V. See Figure 1.

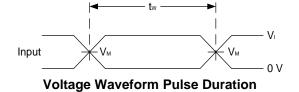
D	From	То	V	T _A	= -40°C to +85	5°C	T _A = -40°C	to +125°C	1111
Parameter	Input	Output	Vcc	Min	Тур	Max	Min	Max	Unit
			1.8V ± 0.15V	1.2	3.8	8.9	1.2	11.2	
				2.5V ± 0.2V	0.8	2.4	5.4	0.8	6.8
t _{pd}	A or B	Υ	2.7V	0.8	3.2	6.0	0.8	7.5	ns
			$3.3V \pm 0.3V$	0.6	2.4	4.9	0.6	6.2	
			5.0V ± 0.5V	0.6	1.8	4.3	0.6	5.5	

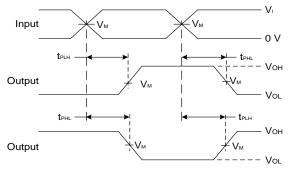


Parameter Measurement Information



V _{cc}	In	puts	V	C	R _L
V CC	Vı	t _r /t _f	• • • • • • • • • • • • • • • • • • •	V _M C _L	
1.8V ± 0.15V	V _{cc}	≤2ns	V _{CC} /2	30pF	1kΩ
2.5V ± 0.2V	Vcc	≤2ns	V _{CC} /2	30pF	500Ω
2.7V	2.7V	≤2.5ns	1.5V	50pF	500Ω
3.3V ± 0.3V	2.7V	≤2.5ns	1.5V	50pF	500Ω
5.0V ± 0.5V	V _{cc}	≤2.5ns	V _{CC} /2	50pF	500Ω





Voltage Waveform Propagation Delay Times Inverting and Non Inverting Outputs

Figure 1. Load Circuit and Voltage Waveforms

A. Includes test lead and test apparatus capacitance.B. All pulses are supplied at pulse repetition rate ≤ 10MHz.

C. Inputs are measured separately one transition per measurement.

D. t_{PLH} and t_{PHL} are the same as $t_{\text{pd}}.$



Marking Information

(Top View)

<u>XX</u>

XX : Identification Code
Y : Year : 0~9
W : Week : A~Z : 1~26 week;
a~z : 27~52 week; z represents
52 and 53 week

X: Internal Code

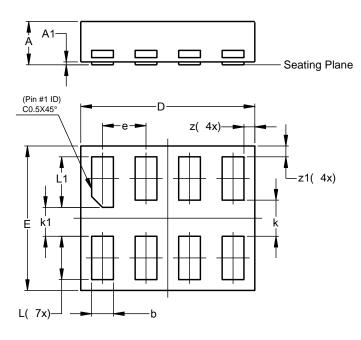
Part Number	Package	Identification Code
74LVC2G02HD4-7	X2-DFN2010-8	9B
74LVC2G02HK3-7	X2-DFN1410-8	9C
74LVC2G02RA3-7	X2-DFN1210-8	9D



X2-DFN1210-8 Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

X2-DFN1210-8

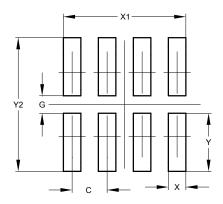


	X2-DFN1210-8								
Dim	Min	Max	Тур						
Α	-	0.35	0.30						
A1	0	0.03	0.02						
b	0.10	0.20	0.15						
D	1.15	1.25	1.20						
Е	0.95	1.05	1.00						
е	-	-	0.30						
k	-	-	0.25						
k1	-	-	0.20						
L	0.25	0.35	0.30						
L1	0.30	0.40	0.35						
Z	0.050	0.100	0.075						
z1	0.050	0.100	0.075						
All I	Dimens	ions in	mm						

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

X2-DFN1210-8



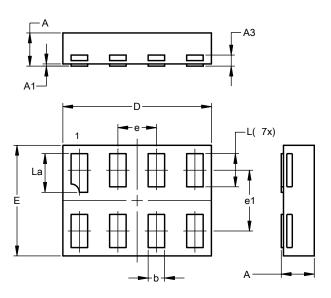
Dimensions	Value (in mm)
C	0.300
G	0.150
Х	0.150
X1	1.050
Y	0.500
Y1	1.150



X2-DFN1410-8 Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

X2-DFN1410-8

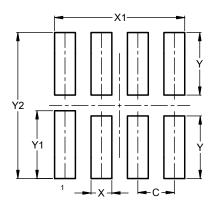


X2-DFN1410-8				
Dim	Min	Max	Тур	
Α	0.30	0.35	0.33	
A1	0.00	0.03	0.02	
A3			0.10	
b	0.12	0.20	0.15	
D	1.30	1.40	1.35	
Е	0.95	1.05	1.00	
е			0.35	
e1			0.55	
L	0.27	0.35	0.30	
L1	0.32	0.40	0.35	
All Dimensions in mm				

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

X2-DFN1410-8



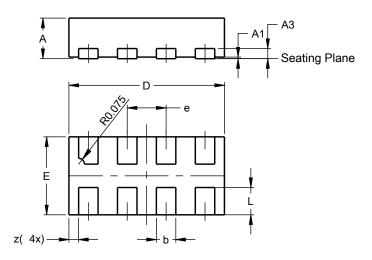
Dimensions	Value	
Dilliensions	(in mm)	
С	0.350	
Х	0.200	
X1	1.250	
Υ	0.600	
Y1	0.650	
Y2	1.400	



X2-DFN2010-8 Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

X2-DFN2010-8

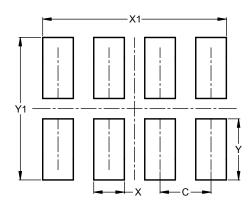


X2-DFN2010-8				
Dim	Min	Max	Тур	
Α		0.40		
A1	0.00	0.05	0.02	
A3			0.13	
b	0.20	0.30	0.25	
D	1.950	2.05	2.00	
E	0.95	1.05	1.00	
е			0.50	
L	0.30	0.40	0.35	
Z			0.125	
All Dimensions in mm				

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

X2-DFN2010-8



Dimensions	Value (in mm)
С	0.500
Х	0.300
X1	1.800
Υ	0.600
V1	1.400



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